

Advanced Power MOSFET

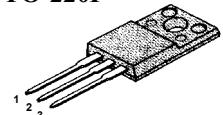
IRFS720A

FEATURES

- Avalanche Rugged Technology
- Rugged Gate Oxide Technology
- Lower Input Capacitance
- Improved Gate Charge
- Extended Safe Operating Area
- Lower Leakage Current : $10\ \mu\text{A}$ (Max.) @ $V_{DS} = 400\text{V}$
- Lower $R_{DS(\text{ON})}$: $1.408\ \Omega$ (Typ.)

$BV_{DSS} = 400\ \text{V}$
 $R_{DS(\text{on})} = 1.8\ \Omega$
 $I_D = 2.8\ \text{A}$

TO-220F



1.Gate 2. Drain 3. Source

Absolute Maximum Ratings

Symbol	Characteristic	Value	Units
V_{DSS}	Drain-to-Source Voltage	400	V
I_D	Continuous Drain Current ($T_C=25\text{ }^\circ\text{C}$)	2.8	A
	Continuous Drain Current ($T_C=100\text{ }^\circ\text{C}$)	1.8	
I_{DM}	Drain Current-Pulsed	13	A
V_{GS}	Gate-to-Source Voltage	± 30	V
E_{AS}	Single Pulsed Avalanche Energy	269	mJ
I_{AR}	Avalanche Current	2.8	A
E_{AR}	Repetitive Avalanche Energy	3.3	mJ
dv/dt	Peak Diode Recovery dv/dt	4.0	V/ns
P_D	Total Power Dissipation ($T_C=25\text{ }^\circ\text{C}$)	33	W
	Linear Derating Factor	0.27	$\text{W}/{}^\circ\text{C}$
T_J, T_{STG}	Operating Junction and Storage Temperature Range	- 55 to +150	${}^\circ\text{C}$
	Maximum Lead Temp. for Soldering Purposes, 1/8" from case for 5-seconds	300	

Thermal Resistance

Symbol	Characteristic	Typ.	Max.	Units
R_{JC}	Junction-to-Case	--	3.74	${}^\circ\text{C}/\text{W}$
	Junction-to-Ambient	--	62.5	

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Fig 1. Output Characteristics

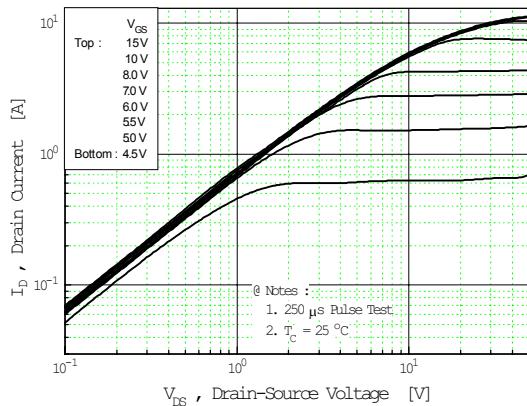


Fig 2. Transfer Characteristics

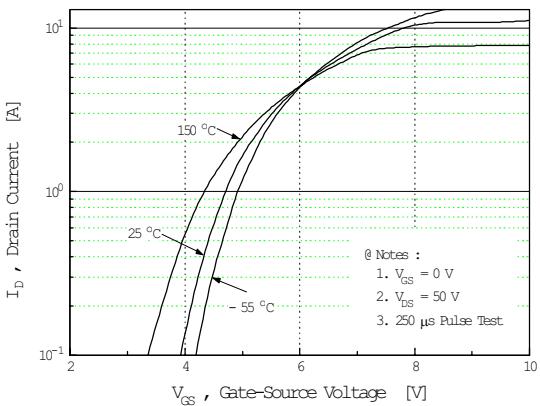


Fig 3. On-Resistance vs. Drain Current

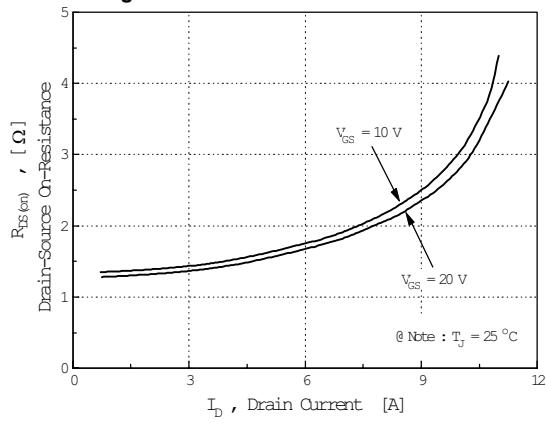


Fig 4. Source-Drain Diode Forward Voltage

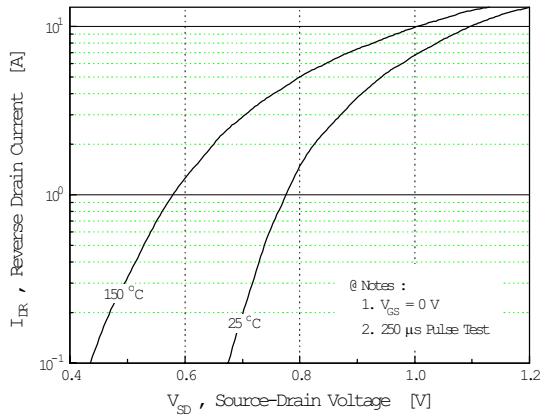


Fig 5. Capacitance vs. Drain-Source Voltage

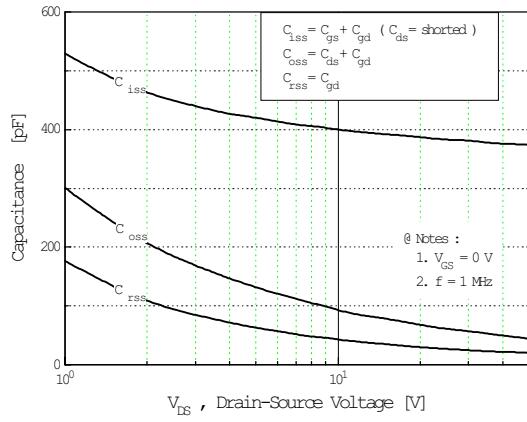
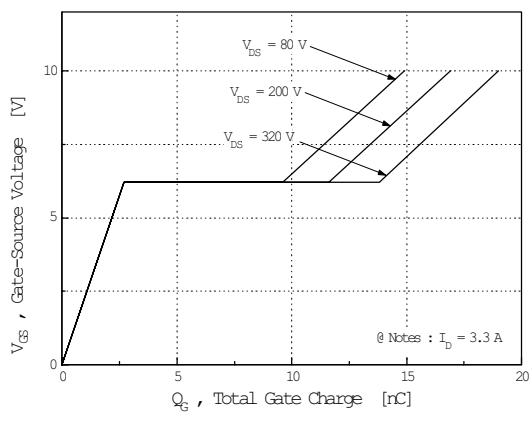


Fig 6. Gate Charge vs. Gate-Source Voltage



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Fig 7. Breakdown Voltage vs. Temperature

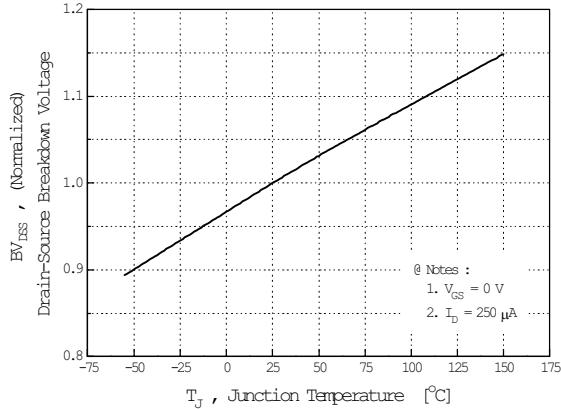


Fig 8. On-Resistance vs. Temperature

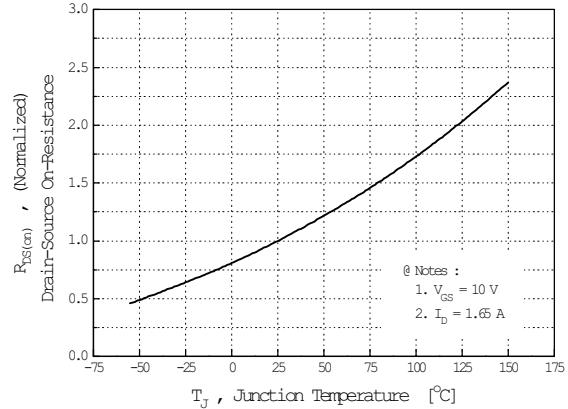


Fig 9. Max. Safe Operating Area

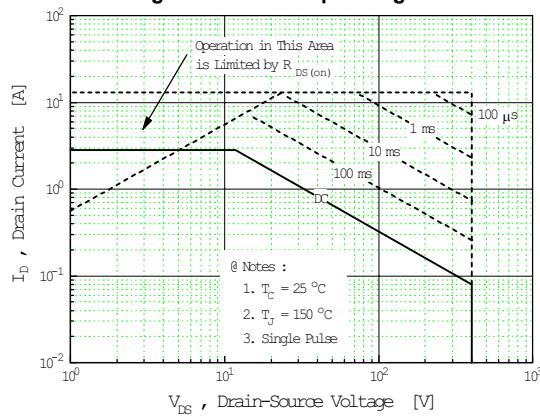


Fig 10. Max. Drain Current vs. Case Temperature

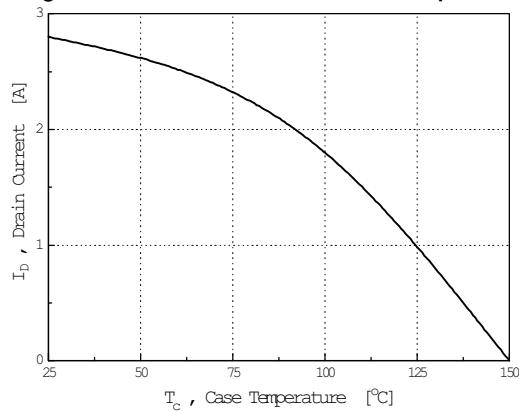


Fig 11. Thermal Response

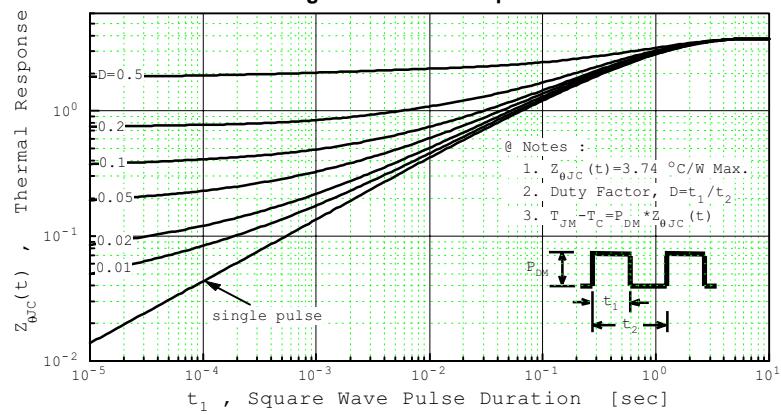


Fig 12. Gate Charge Test Circuit & Waveform

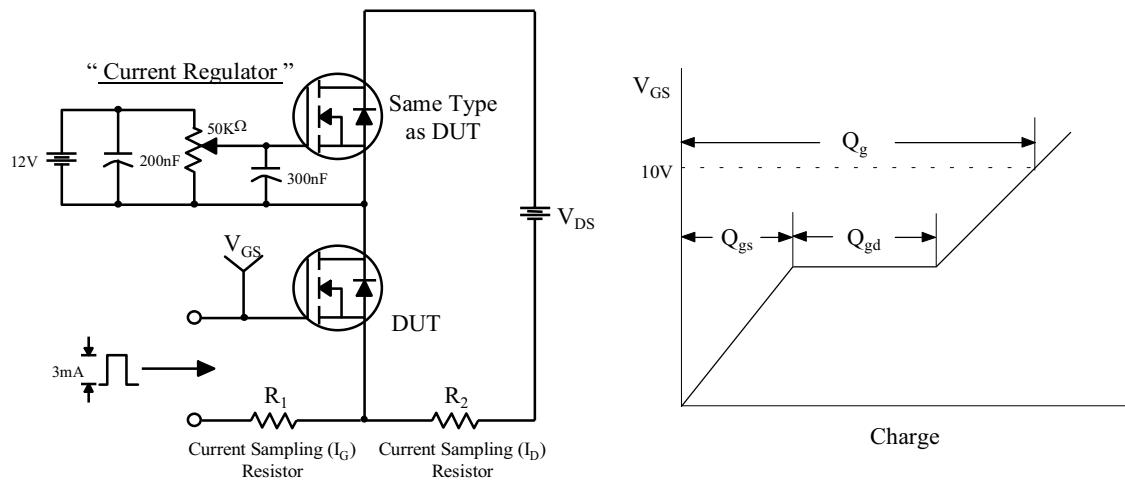


Fig 13. Resistive Switching Test Circuit & Waveforms



Fig 14. Unclamped Inductive Switching Test Circuit & Waveforms



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Fig 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms

